

# Salim Berrada

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/3190992/publications.pdf>

Version: 2024-02-01

15  
papers

141  
citations

1307594

7  
h-index

1588992

8  
g-index

15  
all docs

15  
docs citations

15  
times ranked

97  
citing authors

| #  | ARTICLE   | IF  | CITATIONS |
|----|---|-----|-----------|
| 1  | Simulation of the Impact of Ionized Impurity Scattering on the Total Mobility in Si Nanowire Transistors. <i>Materials</i> , 2019, 12, 124.   | 2.9 | 21        |
| 2  | NESS: new flexible Nano-Electronic Simulation Software. , 2018, , .   |     | 20        |
| 3  | Nano-electronic Simulation Software (NESS): a flexible nano-device simulation platform. <i>Journal of Computational Electronics</i> , 2020, 19, 1031-1046.                          | 2.5 | 20        |
| 4  | Comprehensive Study of Cross-Section Dependent Effective Masses for Silicon Based Gate-All-Around Transistors. <i>Applied Sciences (Switzerland)</i> , 2019, 9, 1895.               | 2.5 | 15        |
| 5  | Investigation of Pt-Salt-Doped-Standalone- Multiwall Carbon Nanotubes for On-Chip Interconnect Applications. <i>IEEE Transactions on Electron Devices</i> , 2019, 66, 2346-2352.    | 3.0 | 13        |
| 6  | Random Dopant-Induced Variability in Si-InAs Nanowire Tunnel FETs: A Quantum Transport Simulation Study. <i>IEEE Electron Device Letters</i> , 2018, 39, 1473-1476.                 | 3.9 | 11        |
| 7  | Understanding Electromigration in Cu-CNT Composite Interconnects: A Multiscale Electrothermal Simulation Study. <i>IEEE Transactions on Electron Devices</i> , 2018, 65, 3884-3892. | 3.0 | 10        |
| 8  | Atomistic- to Circuit-Level Modeling of Doped SWCNT for On-Chip Interconnects. <i>IEEE Nanotechnology Magazine</i> , 2018, 17, 1084-1088.   | 2.0 | 7         |
| 9  | Variability Predictions for the Next Technology Generations of n-type SixGe1~x Nanowire MOSFETs. <i>Micromachines</i> , 2018, 9, 643.   | 2.9 | 7         |
| 10 | Efficient Two-Band based Non-Equilibrium Green's Function Scheme for Modeling Tunneling Nano-Devices. , 2018, , .   |     | 4         |
| 11 | Impact of the Effective Mass on the Mobility in Si Nanowire Transistors. , 2018, , .  |     | 4         |
| 12 | The Impact of Dopant Diffusion on Random Dopant Fluctuation in Si Nanowire FETs: A Quantum Transport Study. , 2018, , .   |     | 3         |
| 13 | Quantum Transport Investigation of Threshold Voltage Variability in Sub-10 nm JunctionlessSi Nanowire FETs. , 2018, , .   |     | 3         |
| 14 | Surface Roughness Scattering in NEGF using self-energy formulation. , 2019, , .   |     | 3         |
| 15 | Nanowire FETs. , 2018, , .  |     | 0         |